

OVERVIEW

The CF5015 series are 2.5V operation crystal oscillator ICs. They are available for frequencies up to 60MHz. The product lineup consists of AL× series for 2.5V exclusive use and BL× series compliant with 2.5V to 5V. The built-in oscillator capacitor of AL× series is large, so that AL× series contribute to improve the frequency stability. For the BL× series, the current consumption and drive level reduced so that they can realize the characteristics easier to design small-sized crystal oscillators. The oscillator circuit of each version is simply constructed, so that it can realize the crystal oscillator with excellent phase noise characteristics. Even if the valued characteristics differ due to the application or the purpose, the selecting from these series for different purposes allows the optimization.

FEATURES

- Operating supply voltage range
 - CF5015AL×: 2.25 to 2.75V
 - CF5015BL×: 2.25 to 5.5V
- Up to 60MHz oscillation frequency range
- – 40 to 85°C operating temperature range
- Oscillation capacitors built-in
 - CF5015AL×: $C_G = 18\text{pF}$, $C_D = 18\text{pF}$
 - CF5015BL×: $C_G = 4\text{pF}$, $C_D = 8\text{pF}$
- Inverter amplifier feedback resistor built-in
- Standby function
 - High impedance in standby mode, oscillator stops
- Low standby current
 - Power-saving pull-up resistor built-in
- f_O , $f_O/2$, $f_O/4$, $f_O/8$, or $f_O/16$ output frequency, determined by internal connection
- CMOS output duty level (1/2VDD)
- Molybdenum-gate CMOS process
- Chip form (CF5015×L×)

SERIES CONFIGURATION

Version	Operating supply voltage range [V]	Recommended oscillation frequency range*1 [MHz]					Built-in capacitance [pF]		Output frequency	Standby mode		
		2.5V operation		3V operation		5V operation	C_G	C_D		Oscillator stop function	Output state	
		$C_L = 15\text{pF}$	$C_L = 30\text{pF}$	$C_L = 15\text{pF}$	$C_L = 30\text{pF}$	$C_L = 30\text{pF}$						
CF5015AL1	2.25 to 2.75	4 to 60	4 to 50	–	–	–	18	18	f_O^{*2}	Yes	Hi-Z	
CF5015AL2												$f_O/2$
CF5015AL3												$f_O/4$
CF5015AL4												$f_O/8$
CF5015AL5												$f_O/16$
CF5015BL1	2.25 to 3.6 4.5 to 5.5	12 to 60	12 to 50	12 to 60	12 to 50	12 to 60	4	8	f_O^{*2}	Yes	Hi-Z	
CF5015BL2												$f_O/2$
CF5015BL3												$f_O/4$
CF5015BL4												$f_O/8$
CF5015BL5												$f_O/16$

*1. The recommended oscillation frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillator frequency band is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

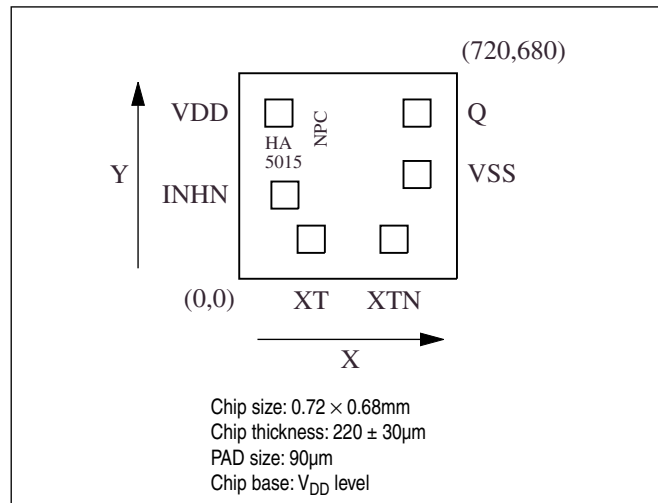
*2. Oscillation frequency

ORDERING INFORMATION

Device	Package
CF5015×L×-2	Chip form

PAD LAYOUT

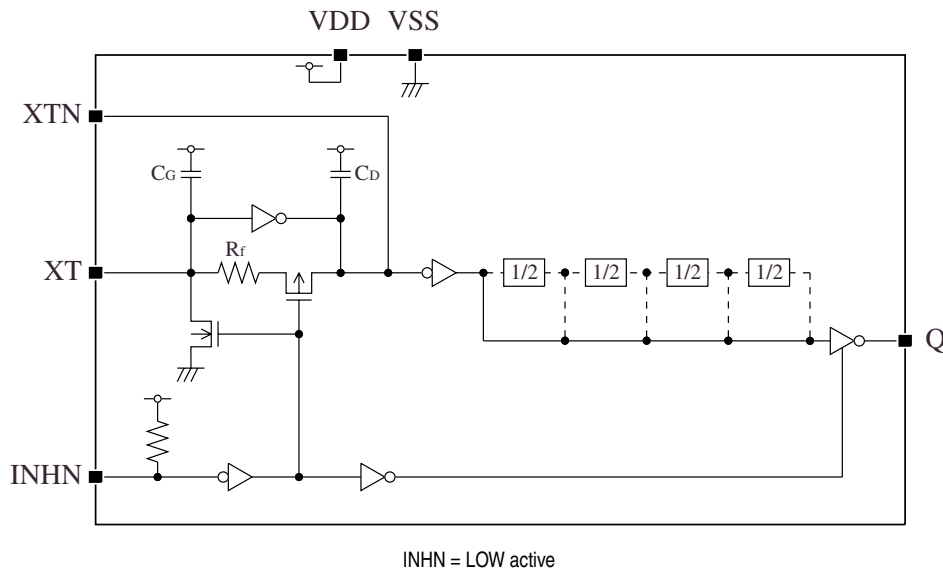
(Unit: μm)



PIN DESCRIPTION and PAD DIMENSIONS

Name	I/O	Description	Pad dimensions [μm]	
			X	Y
INHN	I	Output state control input. High impedance when LOW (oscillator stops). Power-saving pull-up resistor built-in.	151	277
XT	I	Amplifier input	238	131
XTN	O	Amplifier output		
Crystal connection pins. Crystal is connected between XT and XTN.			512	131
VSS	-	Ground	588	345
Q	O	Output. Output frequency ($f_0, f_0/2, f_0/4, f_0/8, f_0/16$) determined by internal connection	588	548
VDD	-	Supply voltage	131	548

BLOCK DIAGRAM



SPECIFICATIONS

Absolute Maximum Ratings

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V_{DD}		-0.5 to +7.0	V
Input voltage range	V_{IN}		-0.5 to $V_{DD} + 0.5$	V
Output voltage range	V_{OUT}		-0.5 to $V_{DD} + 0.5$	V
Operating temperature range	T_{opr}		-40 to +85	°C
Storage temperature range	T_{STG}		-65 to +150	°C
Output current	I_{OUT}		12	mA

Recommended Operating Conditions

2.5V operation (CF5015AL×/CF5015BL×)

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit	
Supply voltage range	V_{DD}		2.25 to 2.75	V	
Input voltage range	V_{IN}		V_{SS} to V_{DD}	V	
Operating temperature range	T_{OPR}		-40 to +85	°C	
Oscillation frequency range	f_O	CF5015AL×	4 to 60	MHz	
		CF5015BL×	12 to 60	MHz	
Output frequency range	f_{OUT}	CF5015AL×	$C_L \leq 15pF$	0.25 to 60	MHz
			$C_L \leq 30pF$	0.25 to 50	MHz
		CF5015BL×	$C_L \leq 15pF$	0.75 to 60	MHz
			$C_L \leq 30pF$	0.75 to 50	MHz

3V operation (CF5015BL×)

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V_{DD}		2.7 to 3.6	V
Input voltage range	V_{IN}		V_{SS} to V_{DD}	V
Operating temperature range	T_{OPR}		-40 to +85	°C
Oscillation frequency range	f_O		12 to 60	MHz
Output frequency range	f_{OUT}	$C_L \leq 15pF$	0.75 to 60	MHz
		$C_L \leq 30pF$	0.75 to 50	MHz

5V operation (CF5015BL×)

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V_{DD}		4.5 to 5.5	V
Input voltage range	V_{IN}		V_{SS} to V_{DD}	V
Operating temperature range	T_{OPR}		-40 to +85	°C
Oscillation frequency range	f_O		12 to 60	MHz
Output frequency range	f_{OUT}	$C_L \leq 30pF$	0.75 to 60	MHz

Electrical Characteristics

2.5V operation (CF5015AL×/CF5015BL×)

$V_{DD} = 2.25$ to 2.75 V, $V_{SS} = 0$ V, $T_a = -40$ to $+85$ °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	V_{OH}	Q: Measurement cct 1, $V_{DD} = 2.25$ V, $I_{OH} = 4$ mA	1.65	1.95	–	V	
LOW-level output voltage	V_{OL}	Q: Measurement cct 1, $V_{DD} = 2.25$ V, $I_{OL} = 4$ mA	–	0.3	0.4	V	
HIGH-level input voltage	V_{IH}	INH N	$0.7V_{DD}$	–	–	V	
LOW-level input voltage	V_{IL}	INH N	–	–	$0.3V_{DD}$	V	
Output leakage current	I_Z	Q: Measurement cct 2, INH N = LOW	$V_{OH} = V_{DD}$	–	–	10	μ A
			$V_{OL} = V_{SS}$	–	–	10	μ A
Current consumption	I_{DD}	Measurement cct 3, load cct 1, INH N = open, $C_L = 15$ pF, $f = 60$ MHz	CF5015AL1	–	5.5	11	mA
			CF5015AL2	–	4	8	mA
			CF5015AL3	–	3	6	mA
			CF5015AL4	–	2.5	5	mA
			CF5015AL5	–	2	4	mA
			CF5015BL1	–	4.5	9	mA
			CF5015BL2	–	3	6	mA
			CF5015BL3	–	2	4	mA
			CF5015BL4	–	1.5	3	mA
CF5015BL5	–	1	2	mA			
Standby current	I_{ST}	Measurement cct 3, INH N = LOW	–	–	3	μ A	
INH N pull-up resistance	R_{UP1}	Measurement cct 4	2	6	12	M Ω	
	R_{UP2}		20	100	200	k Ω	
Feedback resistance	R_f	Measurement cct 5	100	300	600	k Ω	
Built-in capacitance	C_G	Design value. A monitor pattern on a wafer is tested.	CF5015AL×	15.3	18	20.7	pF
			CF5015BL×	3.4	4	4.6	pF
	C_D	Design value. A monitor pattern on a wafer is tested.	CF5015AL×	15.3	18	20.7	pF
			CF5015BL×	6.8	8	9.2	pF

CF5015 series

3V operation (CF5015BL×)

$V_{DD} = 2.7$ to $3.6V$, $V_{SS} = 0V$, $T_a = -40$ to $+85^\circ C$ unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	V_{OH}	Q: Measurement cct 1, $V_{DD} = 2.7V$, $I_{OH} = 4mA$	2.1	2.4	–	V	
LOW-level output voltage	V_{OL}	Q: Measurement cct 1, $V_{DD} = 2.7V$, $I_{OL} = 4mA$	–	0.3	0.4	V	
HIGH-level input voltage	V_{IH}	INH N	$0.7V_{DD}$	–	–	V	
LOW-level input voltage	V_{IL}	INH N	–	–	$0.3V_{DD}$	V	
Output leakage current	I_Z	Q: Measurement cct 2, INH N = LOW	$V_{OH} = V_{DD}$	–	–	10	μA
			$V_{OL} = V_{SS}$	–	–	10	μA
Current consumption	I_{DD}	Measurement cct 3, load cct 1, INH N = open, $C_L = 15pF$, $f = 60MHz$	CF5015BL1	–	5.5	11	mA
			CF5015BL2	–	3	6	mA
			CF5015BL3	–	2	4	mA
			CF5015BL4	–	1.5	3	mA
			CF5015BL5	–	1	2	mA
Standby current	I_{ST}	Measurement cct 3, INH N = LOW	–	–	5	μA	
INH N pull-up resistance	R_{UP1}	Measurement cct 4	1	4	10	$M\Omega$	
	R_{UP2}		20	100	200	$k\Omega$	
Feedback resistance	R_f	Measurement cct 5	100	300	600	$k\Omega$	
Built-in capacitance	C_G	Design value. A monitor pattern on a wafer is tested.	3.4	4	4.6	pF	
	C_D		6.8	8	9.2	pF	

5V operation (CF5015BL×)

$V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $+85^\circ C$ unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	V_{OH}	Q: Measurement cct 1, $V_{DD} = 4.5V$, $I_{OH} = 8mA$	3.9	4.2	–	V	
LOW-level output voltage	V_{OL}	Q: Measurement cct 1, $V_{DD} = 4.5V$, $I_{OL} = 8mA$	–	0.3	0.4	V	
HIGH-level input voltage	V_{IH}	INH N	$0.7V_{DD}$	–	–	V	
LOW-level input voltage	V_{IL}	INH N	–	–	$0.3V_{DD}$	V	
Output leakage current	I_Z	Q: Measurement cct 2, INH N = LOW	$V_{OH} = V_{DD}$	–	–	10	μA
			$V_{OL} = V_{SS}$	–	–	10	μA
Current consumption	I_{DD}	Measurement cct 3, load cct 1, INH N = open, $C_L = 30pF$, $f = 60MHz$	CF5015BL1	–	15	30	mA
			CF5015BL2	–	9.5	19	mA
			CF5015BL3	–	6.5	13	mA
			CF5015BL4	–	5	10	mA
			CF5015BL5	–	4	8	mA
Standby current	I_{ST}	Measurement cct 3, INH N = LOW	–	–	10	μA	
INH N pull-up resistance	R_{UP1}	Measurement cct 4	0.5	2	8	$M\Omega$	
	R_{UP2}		10	50	150	$k\Omega$	
Feedback resistance	R_f	Measurement cct 5	100	300	600	$k\Omega$	
Built-in capacitance	C_G	Design value. A monitor pattern on a wafer is tested.	3.4	4	4.6	pF	
	C_D		6.8	8	9.2	pF	

Switching Characteristics

2.5V operation (CF5015AL×/CF5015BL×)

$V_{DD} = 2.25$ to $2.75V$, $V_{SS} = 0V$, $T_a = -40$ to $+85^\circ C$ unless otherwise noted.

Parameter	Symbol	Condition		Rating			Unit
				min	typ	max	
Output rise time	t_{r1}	Measurement cct 3, load cct 1, $0.1V_{DD}$ to $0.9V_{DD}$	$C_L = 15pF$	–	3	6	ns
	t_{r2}		$C_L = 30pF$	–	5	10	
Output fall time	t_{f1}	Measurement cct 3, load cct 1, $0.9V_{DD}$ to $0.1V_{DD}$	$C_L = 15pF$	–	3	6	ns
	t_{f2}		$C_L = 30pF$	–	5	10	
Output duty cycle ^{*1}	Duty1	Measurement cct 3, load cct 1, $V_{DD} = 2.5V$, $T_a = 25^\circ C$	$C_L = 15pF$ $f = 60MHz$	45	–	55	%
	Duty2		$C_L = 30pF$ $f = 50MHz$	45	–	55	%
Output disable delay time ^{*2}	t_{PLZ}	Measurement cct 6, load cct 1, $V_{DD} = 2.5V$, $T_a = 25^\circ C$,		–	–	100	ns
Output enable delay time ^{*2}	t_{PZL}	$C_L = 15pF$		–	–	100	ns

*1. The duty cycle characteristic is checked the sample chips of each production lot.

*2. Oscillator stop function is built-in. When INHN goes LOW, normal output stops. When INHN goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

3V operation (CF5015BL×)

$V_{DD} = 2.7$ to $3.6V$, $V_{SS} = 0V$, $T_a = -40$ to $+85^\circ C$ unless otherwise noted.

Parameter	Symbol	Condition		Rating			Unit
				min	typ	max	
Output rise time	t_{r1}	Measurement cct 3, load cct 1, $0.1V_{DD}$ to $0.9V_{DD}$	$C_L = 15pF$	–	2.5	5	ns
	t_{r2}		$C_L = 30pF$	–	4	8	
Output fall time	t_{f1}	Measurement cct 3, load cct 1, $0.9V_{DD}$ to $0.1V_{DD}$	$C_L = 15pF$	–	2.5	5	ns
	t_{f2}		$C_L = 30pF$	–	4	8	
Output duty cycle ^{*1}	Duty1	Measurement cct 3, load cct 1, $V_{DD} = 3.0V$, $T_a = 25^\circ C$	$C_L = 15pF$ $f = 60MHz$	45	–	55	%
	Duty2		$C_L = 30pF$ $f = 50MHz$	45	–	55	%
Output disable delay time ^{*2}	t_{PLZ}	Measurement cct 6, load cct 1, $V_{DD} = 3.0V$, $T_a = 25^\circ C$,		–	–	100	ns
Output enable delay time ^{*2}	t_{PZL}	$C_L = 15pF$		–	–	100	ns

*1. The duty cycle characteristic is checked the sample chips of each production lot.

*2. Oscillator stop function is built-in. When INHN goes LOW, normal output stops. When INHN goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

5V operation (CF5015BL×)

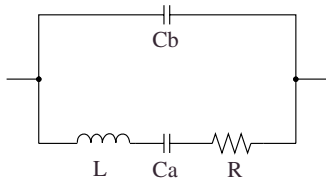
$V_{DD} = 4.5$ to $5.5V$, $V_{SS} = 0V$, $T_a = -40$ to $+85^\circ C$ unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
Output rise time	t_{r1}	Measurement cct 3, load cct 1, $0.1V_{DD}$ to $0.9V_{DD}$	$C_L = 15pF$	–	1.7	3.4	ns
	t_{r2}		$C_L = 30pF$	–	3	6	
Output fall time	t_{f1}	Measurement cct 3, load cct 1, $0.9V_{DD}$ to $0.1V_{DD}$	$C_L = 15pF$	–	1.7	3.4	ns
	t_{f2}		$C_L = 30pF$	–	3	6	
Output duty cycle*1	Duty1	Measurement cct 3, load cct 1, $V_{DD} = 5.0V$, $T_a = 25^\circ C$	$C_L = 30pF$ $f = 60MHz$	45	–	55	%
Output disable delay time*2	t_{PLZ}	Measurement cct 6, load cct 1, $V_{DD} = 5.0V$, $T_a = 25^\circ C$, $C_L = 15pF$		–	–	100	ns
Output enable delay time*2	t_{PZL}			–	–	100	ns

*1. The duty cycle characteristic is checked the sample chips of each production lot.

*2. Oscillator stop function is built-in. When INHN goes LOW, normal output stops. When INHN goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

Current consumption and Output waveform with NPC’s standard crystal



f [MHz]	R [Ω]	L [mH]	Ca [fF]	Cb [pF]
50	16.12	6.88	1.48	1.18
60*	–	–	–	–

* The 60MHz crystal parameter is confidential.

FUNCTIONAL DESCRIPTION

Standby Function

When INHN goes LOW, the oscillator stops and the oscillator output on Q becomes high impedance.

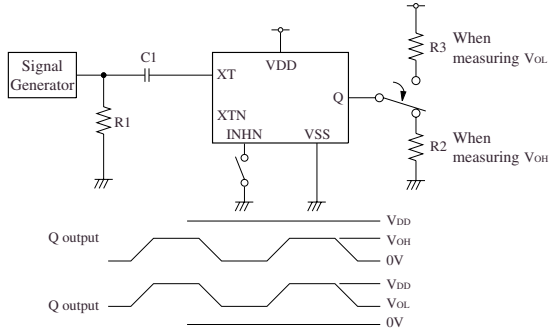
INHN	Q	Oscillator
HIGH (or open)	Any f_O , $f_O/2$, $f_O/4$, $f_O/8$ or $f_O/16$ output frequency	Normal operation
LOW	High impedance	Stopped

Power-saving Pull-up Resistor

The INHN pull-up resistance changes in response to the input level (HIGH or LOW). When INHN goes LOW (standby state), the pull-up resistance becomes large to reduce the current consumption during standby.

MEASUREMENT CIRCUITS

Measurement cct 1



2Vp-p, 10MHz sine wave input signal

C1: 0.001 μ F

R1: 50 Ω

R2: 413 Ω (2.5V operation)

525 Ω (3V operation)

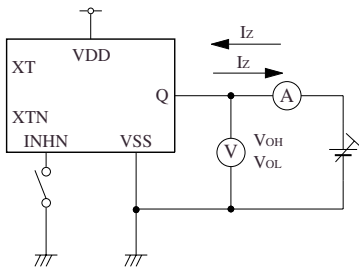
488 Ω (5V operation)

R3: 462 Ω (2.5V operation)

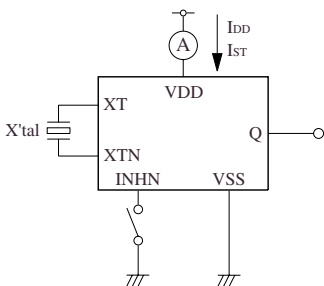
575 Ω (3V operation)

512 Ω (5V operation)

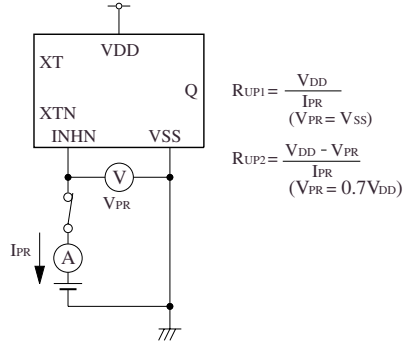
Measurement cct 2



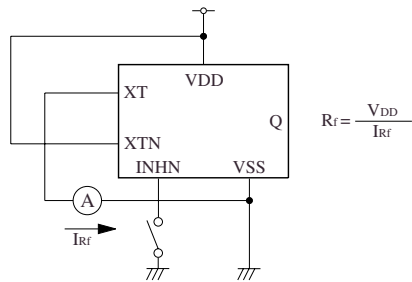
Measurement cct 3



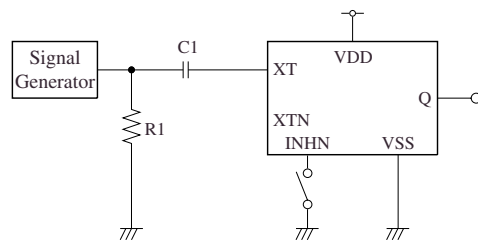
Measurement cct 4



Measurement cct 5



Measurement cct 6

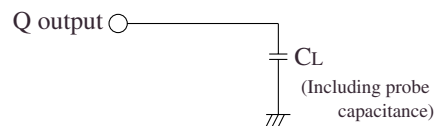


2Vp-p, 10MHz sine wave input signal

C1: 0.001 μ F

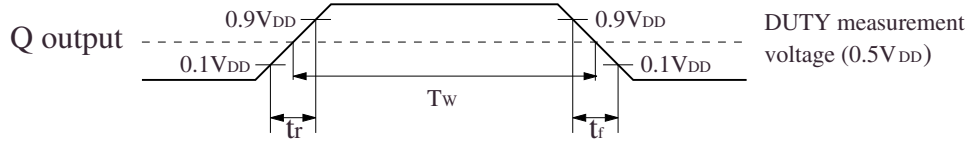
R1: 50 Ω

Load cct 1

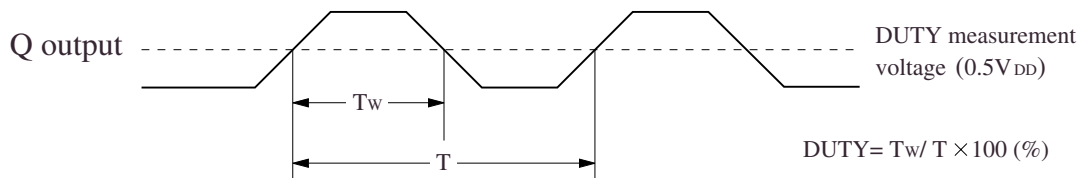


Switching Time Measurement Waveform

Output duty level

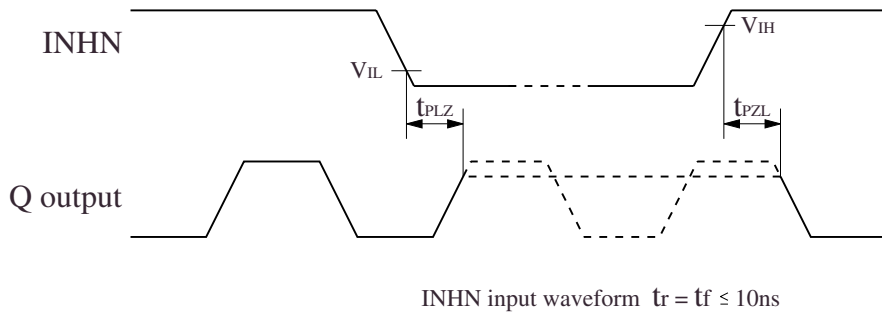


Output duty cycle



Output Enable/Disable Delay

when the device is in standby, the oscillator stops. When standby is released, the oscillator starts and stable oscillator output occurs after a short delay.



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The logo for SEIKO NPC CORPORATION, consisting of the letters 'NPC' in a bold, black, sans-serif font.

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